

ZnAl₂O₄-Functionalized Zinc Oxide Microstructures for Highly Selective Hydrogen Gas Sensing Applications

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Abstract

In this work, a simple method of ZnAl₂O₄-functionalization of ZnO microstructures is presented. The different characterization methods (structural, chemical, and micro-Raman) demonstrated the presence of only ZnO and ZnAl₂O₄ crystalline phases. ZnAl₂O₄ nano-crystallites grow on the surfaces of ZnO 3D microstructures having diameters of 50–100nm and with high density. Transmission electron microscopy (TEM) and high-resolution TEM (HRTEM) results clearly show ZnAl₂O₄ crystallites functionalizing zinc oxide tetrapod arms. The individual structures (microwires (MWs) and three-dimensional (3D) tetrapods (Ts)) are integrated into functional devices, suitable for gas sensing applications. All devices show excellent hydrogen gas selectivity at relatively low operating temperature in the range of 25–100°C. The highest gas sensing performances are obtained based on individual ZnAl₂O₄-functionalized ZnO tetrapods (ZnAl₂O₄/ZnO-T, with an arm diameter (D) of ≈400nm) and a response of ≈2 at 25°C to 100ppm of hydrogen gas (H₂), while a ZnAl₂O₄/ZnO-MW (D≈400nm) shows only a response of ≈1.1. The Al-doped ZnO MW (D≈400nm) without ZnAl₂O₄ elaborated in another work, chosen only for comparison reason, shows no response up to 800ppm H₂ gas concentration. A gas sensing mechanism is proposed for a single ZnAl₂O₄/ZnO-T microstructure based sensor. The obtained results on ZnAl₂O₄/ZnO-T-based devices is superior to many reported performances of other individual metal oxide nanostructures with much lower diameter, showing promising results for room temperature H₂ gas sensing applications.